Autonics

- Observe all 'Safety Considerations' for safe and proper operation to avoid hazards.
- ▲ symbol indicates caution due to special circumstances in which hazards may occur.

Marning Failure to follow instructions may result in serious injury or death.

- 01. Fail-safe device must be installed when using the unit with machinery that may cause serious injury or substantial economic loss. (e.g., nuclear power control, medical equipment, ships, vehicles, railways, aircraft, combustion apparatus, safety equipment, crime/disaster prevention devices, etc.)
- Failure to follow this instruction may result in personal injury, fire or economic loss 02. Do not use the unit in the place where flammable/explosive/corrosive gas, high humidity, direct sunlight, radiant heat, vibration, impact, or salinity may be present.

Failure to follow this instruction may result in explosion or fire. 03. Do not disassemble or modify the unit.

- Failure to follow this instruction may result in fire.
- 04. Do not connect, repair, or inspect the unit while connected to a power source. Failure to follow this instruction may result in fire.
- 05. Check 'Connections' before wiring. Failure to follow this instruction may result in fire.

Safety Considerations

Caution Failure to follow instructions may result in injury or product damage.

- 01. Use the unit within the rated specifications.
- Failure to follow this instruction may result in fire or shortening the life cycle of the product. 02. Use dry cloth to clean the unit, and do not use water or organic solvent.
- Failure to follow this instruction may result in fire or electric shock 03. When connecting the power input and output, use AWG 22-16 cable and check the connecting method of crimp terminal.
- Failure to follow this instruction may result in fire or malfunction due to contact failure. 04. Keep metal chip, dust, and wire residue from flowing into the unit.
- Failure to follow this instruction may result in fire or product damag 05. Do not connect or disconnect connector (terminal) wire or power, when the product is operating.

Failure to follow this instruction may result in fire or malfunction of the product.

Cautions during Use

- · Follow instructions in 'Cautions during Use'. Otherwise, It may cause unexpected accidents.
- BUS power and I/O power should be insulated by the individually insulated power device. · Power supply should be insulated and limited voltage/current or Class 2, SELV power supply
- device • Keep away from high voltage lines or power lines to prevent inductive noise. In case installing power line and input signal line closely, use line filter or varistor at power line and shielded wire at input signal line. For stable operation, use shield wire and ferrite core, when wiring
- communication wire, power wire, or signal wire. Do not use near the equipment which generates strong magnetic force or high frequency noise. Use the rated standard cables and connectors. Do not apply excessive power when
- connecting or disconnecting the connectors of the product
- Do not touch the module communication connector part of the base.
- Do not connect, or remove the base while connected to a power source. For removing the terminal, body or base, do not operate units for a long time without it.
- This unit may be used in the following environments. - Indoors (in the environment condition rated in 'Specifications') - Altitude max. 2,000 m
- Pollution degree 2
- Installation category II

Slim Remote I/O



ARIO Series PRODUCT MANUAL

For your safety, read and follow the considerations written in the instruction manual, other manuals and Autonics website.

The specifications, dimensions, etc. are subject to change without notice for product improvement. Some models may be discontinued without notice.

Features

- I/O supported based on industrial Ethernet / Fieldbus serial communication for Smart Factory
- Sequential multiple I/O distribution control via PLC, Industrial PC, etc.
- Coupler
- Modbus TCP compatible, Modbus RTU compatible
- : Various Input / Output Modules, Power Modules

- : Maintenance and setting can be restored automatically by replacing terminal and body during operation
- Push-in connection method
- : Easy wire connection without tools helps reducing workload
- · Expanded user convenience with DAQMaster, a device integration management program
- Module setting, real time control and monitoring / diagnosis of input / output signal (except ARIO-C-PN/PB)
- Product selection and placement through virtual mode, offering recommended sorting



- : Supports a total of 8 different communications
- EtherCAT, CC-Link, ProfiNet, ProfiBus, Ethernet/IP, DeviceNet,
- Modules
- Remote ABUS/ I/O power, Digital input/output (4/8 CH), Analog input/output (2/4 CH), Temperature input (4 CH)
- Up to 64 modules can be extended (depending on communication)
- Hot-swap function

Ordering Information

This is only for reference, the actual product does not support all combinations. For selecting the specified model, follow the Autonics website.

Coupler

	-				
ARIO -	С	-	0		
Protocol					
EC: EtherCAT					
CL: CC-Link					
PN: ProfiNet					
PB: ProfiBus					
EI: Ethernet/IF)				
DN: DeviceNet	t				
MT: Modbus T	CP comp	oatible			
MR: Modbus R	TU comp	oatible			

I/O module

ARIO - S - 🕻	00
● I/O signal	2 The number of channel
DI: Digital input	02: 2 CH
DO: Digital output	04: 4 CH
Al: Analog input	08: 8 CH
AO: Analog output	
I/O specifications	
N: NPN	
P: PNP	

N: NPN P: PNP V1: Voltage (-10 to 10 VDC==) V2: Voltage (0 to 10 VDC==) C1: Current (0 to 20 mA) C2: Current (4 to 20 mA) TC: Thermocouple RTD: Resistance thermometer

Power module

ARIO	-	Ρ	-	0				

• Power supply

B: Bus power

- F: I/O power
- T: Terminal power

Product Components

Coupler

Model	ARIO-C-EC	ARIO-C-CL	ARIO-C-PN	ARIO-C-PB		
Product components	Product, instruction manual					
End module	×1	×1	×1	×1		
Communication connector	-	×1	-	-		
Terminating resistance	-	× 2	-	-		
Model	ARIO-C-EI	ARIO-C-DN	ARIO-C-MT	ARIO-C-MR		
Product components	Product, instruc	tion manual				
End module	×1	×1	×1	×1		
Communication connector	-	×1	-	×1		
Terminating resistance	-	× 2	-	× 2		

Module

• Product

Instruction manual

Manual

For proper use of the product, refer to the manuals and be sure to follow the safety considerations in the manuals.

Download the manuals from the Autonics website.

Software

Download the installation file and the manuals from the Autonics website.

DAQMaster

It is the comprehensive device management program for Autonics' products, providing parameter setting, monitoring and data management.

Sold Separately

- Terminal and base of the coupler
- Terminal, body, and base of the module

Dimensions

- Unit: mm, For the detailed drawings, follow the Autonics website.
- It may differ depending on the model.

Coupler



Model	A
ARIO-C-EC/EI/PN/MT	39
ARIO-C-DN/CL/MR	36.2
ARIO-C-PB	38.2









Module

A Status indicatorB Channel indicator





Unit Descriptions

- It may differ depending on the model.
- Refer to the 'Dimensions' in case of the module.

Coupler 1<

01. Communication connector

ARIO-C-EC/PN/EI/MT	ARIO-C-PB	ARIO-C-CL/DN/MR
RJ-45 connectors: 2	D SUB-9 Pin	5-pin PCB Connector
	oo	

02. Communication setting switch

ARIO-C-EC	ARIO-C-CL/DN	The others
None	Decimal rotary switches: 3 (communication speed, address (×10, ×1))	Hexagonal rotary switches: 2 (address (×16, ×1))

Cautions during Installation

\triangle Follow the regulations below to configure the modules. For the configuration of the unit, refer to the figure below.

- $\underline{\mathbb{A}}$ For more information, be sure to see the 'Manual of ARIO Series.'
- The number of connected modules: up to 32 or 64 modules
- The length of connection: 768 mm (include the power module and except the coupler/ end modules)
- 8 digital I/O modules and 4 analog/special modules can be connected to ARIO-P-B or ARIO-P-F1.
- Do not connect the temperature input module at the left and right side of the power module.
- If you placed the coupler on the left side, recommend installing the modules with a bit or 1-byte type on the right side of the I/O module with word type.





Specifications

Coupler

M. J.I						
Model	ARIO-C-EC	ARIO-C-CL	ARIO-C-PN	ARIO-C-PB		
Protocol	EtherCAT.	CC-Link	and the second s			
Transfer rate	100 Mbps	10 Mbps	100 Mbps	12 Mbps		
Max. connections	≤ 64	≤ 32	≤ 64	≤ 32		
for modules	1024 D: +-	= == 512 D: +-	1024 0: +-	400 D +-		
Memory map	1024 Byte	DIT RALE	1024 Byte	488 Byte		
connector	RJ45 × 2	5-pin PCB	RJ45 × 2	9-pin D SUB		
Setting connector	USB 2.0 type Micr	ю В				
Model	ARIO-C-FI	ARIO-C-DN	ARIO-C-MT	ARIO-C-MR		
Brotocol		Device Mat	ModbusTCP	ModbusRTU		
FIOLOCOL	EtherNet/IP	DeviceNet	compatible	compatible		
Transfer rate	10/100 Mbps	500 kbps	10/100 Mbps	115.2 kbps		
for modules	≤ 64	\leq 32	≤ 64	\leq 32		
Memory map	1008 Byte	510 Byte	1024 Byte	512 Byte		
Communication	R 145 X 2	5-nin PCB	R 145 × 2	5-nin PCB		
connector	1010 / 2	5 pint CD	1010 / 2	5 pint 65		
Setting connector	USB 2.0 type Micr	o B				
	• ABUS (external c	onsump.): 24 VDC=	=,≤400 mA			
Power supply	(≤ 9.6 W, couple	$er + module, \le 200$	mA/CH, 2 CH/COM)		
	ABUS (internal si	$upply$): 5 VDC==, \leq	$960 \text{ mA} (\le 4.8 \text{ W, r})$	nodule)		
Power	• 1/U. 24 VDC==, ≥	- +,000 IIIA (≥ 90 W)				
consumption	24 VDC==, standb	y/run: 200 mA, Max.	load: 400 mA (cou	pler max. load)		
Module						
						
Type	Digital input Digital output					
Channel			ARIO-S-DO			
I/O common	NPN, PNP model					
I/O signal level	24 VDC== ± 10 %	1				
Input voltage	Turn ON: ≥ 7 VDC)=	_			
Output leakage	Turn OFF: $\leq 0.4 \text{ V}$	DC==				
voltage	-		≤ 1.2 VDC==			
I/O current	6 mA/CH		-			
Rated output						
current	-		500 mA/CH			
Power consumption	ABUS: 5 VDC==, ≤	≤ 100 mA (≤ 0.5 W)				
conouniption	ABUS: 5 VDC, \sim 100 IIIA (\sim 0.5 W)					
On delay time	\leq 0.5 ms					
On delay time Off delay time	\leq 0.5 ms \leq 1.5 ms					
On delay time Off delay time Internal	$\leq 0.5 \mathrm{ms}$ $\leq 1.5 \mathrm{ms}$					
On delay time Off delay time Internal transmission speed	≤ 0.5 ms ≤ 1.5 ms 4 Mbps					
On delay time Off delay time Internal transmission speed Insulation	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps I/O to inner circuit	t: photocoupler insi	ulated			
On delay time Off delay time Internal transmission speed Insulation	≤ 0.5 ms ≤ 1.5 ms 4 Mbps I/O to inner circuit	t: photocoupler insi	ulated			
On delay time Off delay time Internal transmission speed Insulation Type Model	≤ 0.5 ms ≤ 1.5 ms 4 Mbps I/O to inner circuii Analog input ARIO-S-AI_V1	t: photocoupler insi	ulated	ARIO-S-AI□C2		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel	≤ 0.5 ms ≤ 1.5 ms 4 Mbps 1/0 to inner circuit Analog input ARIO-S-AI_V1 2 CH, 4 CH model	t: photocoupler insi ARIO-S-AI□V2	ulated ARIO-S-AI□C1	ARIO-S-AI C2		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method	\leq 0.5 ms \leq 1.5 ms 4 Mbps 1/O to inner circuit Analog input ARIO-S-AI V1 2 CH, 4 CH model Voltage input	t: photocoupler insi ARIO-S-AI□V2	ulated ARIO-S-AI□C1 Current input	ARIO-S-AI C2		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range	≤ 0.5 ms ≤ 1.5 ms 4 Mbps 1/O to inner circuit Analog input ARIO-S-AI□V1 2 CH, 4 CH model Voltage input -10 to 10 VDC=	t: photocoupler insi ARIO-S-AI V2	ulated ARIO-S-AI□C1 Current input 0 to 20 mA	ARIO-S-AI□C2 4 to 20 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy	≤ 0.5 ms ≤ 1.5 ms 4 Mbps 1/O to inner circuit Analog input ARIO-S-AI□V1 2 CH, 4 CH model Voltage input -10 to 10 VDC== • Room temperatu	t: photocoupler insi ARIO-S-AI□V2 0 to 10 VDC=- ure: PV ±0.3% F.S. perature: PV ±0.68	ARIO-S-AI□C1 Current input 0 to 20 mA	ARIO-S-AI□C2 4 to 20 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps 4 Mbps 1/0 to inner circuit Analog input ARIO-S-AI V1 2 CH, 4 CH model Voltage input -10 to 10 VDC= • Room temperatt • Out of room tem $\geq 1 \text{ M}\Omega$	t: photocoupler insi ARIO-S-AI□V2 0 to 10 VDC= ure: PV ±0.3% F.S. uperature: PV ±0.6%	ulated ARIO-S-AI□C1 Current input 0 to 20 mA % F.S. ≤ 250 Ω	ARIO-S-AI□C2 4 to 20 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps 4 Mbps 4 Mbps 4 More circuit Analog input ARIO-S-AI V1 2 CH, 4 CH model Voltage input -10 to 10 VDC= • Room temperatt • Out of room temperatt • Out of room temperatt $\leq 1.4 \text{ or } > 14 \text{ or }$	t: photocoupler insi ARIO-S-AI□V2 0 to 10 VDC== ure: PV ±0.3% F.S. sperature: PV ±0.6%	ARIO-S-AI□C1 Current input 0 to 20 mA % F.S. ≤ 250 Ω ≥ 1 mA	ARIO-S-AI□C2 4 to 20 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator ON	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps 4 Mbps 4 Mbps 4 More circuit ARIO-S-AI V1 2 CH, 4 CH model Voltage input -10 to 10 VDC= • Room temperatt • Out of room tem $\geq 1 \text{ M}\Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$	t: photocoupler insu ARIO-S-AI \Box V2 0 to 10 VDC= ure: PV ±0.3% F.S. sperature: PV ±0.6% \geq 1 V	ulated ARIO-S-AI□C1 Current input 0 to 20 mA % F.S. ≤ 250 Ω ≥ 1 mA	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator ON Resolution	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $1/0 \text{ to inner circuit}$ $A \text{ RIO-S-AI} V1$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage input$ $-10 \text{ to } 10 \text{ VDC} =$ $-0 \text{ to for momenter}$ $\geq 1 \text{ M} \Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12 -bit	t: photocoupler insi ARIO-S-AI \Box V2 0 to 10 VDC= ure: PV \pm 0.3% F.S. sperature: PV \pm 0.6% \geq 1V \leq 180 mA (< 0.9 W	ulated ARIO-S-AI□C1 Current input 0 to 20 mA % F.S. ≤ 250 Ω ≥ 1 mA	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $1/0 \text{ to inner circuit}$ $A \text{ RIO-S-AI} \cup V1$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage input$ $-10 \text{ to } 10 \text{ VDC} =$ $-Room temperater$ $\geq 1 \text{ M} \Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12 -bit $-A \text{BUS: 5 VDC} =, z$	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. sperature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W 15 mA (\leq 0.36 W)	ulated ARIO-S-AI□C1 Current input 0 to 20 mA % F.S. ≤ 250 Ω ≥ 1 mA	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $1/0 \text{ to inner circuit}$ $A \text{ alog input}$ $A \text{ RIO-S-AI} \square \text{ V1}$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage input$ $-10 \text{ to 10 VDC} = 1$ $Room temperative$ $\geq 1 \text{ M} \Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12 -bit $-A \text{ BUS: 5 VDC} = , \leq 1 \text{ -10}$	t: photocoupler insi ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. sperature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W 15 mA (\leq 0.36 W)	ulated ARIO-S-AI□C1 Current input 0 to 20 mA % F.S. ≤ 250 Ω ≥ 1 mA	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed	$ \leq 0.5 \text{ ms} \\ \leq 1.5 \text{ ms} \\ 4 \text{ Mbps} \\ 1/0 \text{ to inner circuit} \\ A alog input \\ A RIO-S-AI V1 \\ 2 CH, 4 CH model \\ Voltage input \\ -10 to 10 VDC = \\ \cdot Room temperatt \\ -0 ut of room tem \\ \geq 1 M \Omega \\ \leq -1 \text{ V or } \geq 1 \text{ V} \\ 12 \text{ -bit} \\ \cdot A BUS: 5 \text{ VDC = }, \leq \\ 4 \text{ Mbps} \\ \end{tabular}$	t: photocoupler insu ARIO-S-AI \Box V2 0 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W \leq 15 mA (\leq 0.36 W)	ARIO-S-AI□C1 Current input 0 to 20 mA % F.S. ≤ 250 Ω ≥ 1 mA)	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $I/O \text{ to inner circuit}$ Analog input ARIO-S-AI V1 2 CH, 4 CH model Voltage input -10 to 10 VDC= ·Room temperatt ·Out of room tem $\geq 1 \text{ M}\Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12-bit ·ABUS: 5 VDC=, ; ·I/O: 24 VDC=, ≤ 4 Mbps ·I/O to inner circu	t: photocoupler insi ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. sperature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W \leq 15 mA (\leq 0.36 W) it: photocoupler insi	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation	$ \leq 0.5 \text{ ms} \\ \leq 1.5 \text{ ms} \\ 4 \text{ Mbps} \\ 1/0 \text{ to inner circuit} \\ A alog input \\ A RIO-S-AI \vert V1 \\ 2 CH, 4 CH model \\ Voltage input \\ -10 to 10 VDC = \\ \cdot Room temperate \\ -0 ut of room term \\ \geq 1 M \Omega \\ \leq -1 \text{ V or } \geq 1 \text{ V} \\ 12 \text{ bit} \\ \cdot A BUS: 5 VDC = , : \\ \cdot 1/O: 24 VDC = , \leq \\ 4 \text{ Mbps} \\ \cdot 1/0 \text{ to inner circu} \\ \cdot Between channel \\ \cdot 100 \text{ to inner circu} \\ \cdot 100 to inner circu \\ \cdot 100 \text{ to inner circu \\ \cdot 10$	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W 15 mA (\leq 0.36 W) it: photocoupler insulated	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $I/O \text{ to inner circuit}$ ARIO-S-AI \square V1 $2 \text{ CH, 4 \text{ CH model}}$ Voltage input -10 to 10 VDC= ·Room temperatt ·Out of room tem $\geq 1 \text{ M}\Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12-bit ·ABUS: 5 VDC=,; ·I/O: 24 VDC=, \leq 4 Mbps ·I/O to inner circu ·Between channe Analog output	t: photocoupler insu ARIO-S-AI \Box V2 0 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W i 15 mA (\leq 0.36 W) it: photocoupler in: els: non-insulated	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation Type Model	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $I/0 \text{ to inner circuit}$ $A \text{ RiO-S-Al} V1$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage input$ $-10 \text{ to 10 VDC} =$ $\cdot \text{Room temperatt}$ $\circ \text{Out of room term}$ $\geq 1 \text{ M}\Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12 cbit $\cdot \text{ ABUS: 5 VDC} =, \leq$ 4 Mbps $\cdot I/0 \text{ to inner circu}$ $\cdot \text{ Between channe}$ $A \text{ ralog output}$ $A \text{ RIO-S-AO} V1$	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W 15 mA (\leq 0.36 W) it: photocoupler insulated ARIO-S-AO \Box V2	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated ARIO-S-AO \Box C1	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation Type Model Channel	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $I/0 \text{ to inner circuit}$ ARIO-S-AI \square V1 $2 \text{ CH, 4 \text{ CH model}}$ Voltage input -10 to 10 VDC= ·Room temperatt ·Out of room tem $\geq 1 \text{ M}\Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12-bit ·ABUS: 5 VDC=,; ·I/O: 24 VDC=, \leq 4 Mbps ·I/O to inner circu ·Between channer Analog output ARIO-S-AO \square V1 2 CH, 4 CH model	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W 15 mA (\leq 0.36 W) it: photocoupler insulated ARIO-S-AO \Box V2	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated ARIO-S-AO \Box C1	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation Type Model Channel Output method	\leq 0.5 ms \leq 1.5 ms 4 Mbps 1/O to inner circuit Analog input ARIO-S-AI \square V1 2 CH, 4 CH model Voltage input -10 to 10 VDC= · Room temperatu · Out of room tem \geq 1 M Ω \leq -1 V or \geq 1 V 12-bit · ABUS: 5 VDC=, ; · 1/O: 24 VDC=, \leq 4 Mbps · 1/O to inner circu · Between channer Analog output ARIO-S-AO \square V1 2 CH, 4 CH model Voltage output	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W \leq 15 mA (\leq 0.36 W) it: photocoupler insulated ARIO-S-AO \Box V2	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated ARIO-S-AO \Box C1 Current output	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input range Accuracy Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation Type Model Channel Output method Output method	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $I/0 \text{ to inner circuit}$ ARIO-S-AI V1 $2 \text{ CH, 4 \text{ CH model}}$ Voltage input $-10 \text{ to 10 VDC} =$ $Room temperatt$ $Out of room term \geq 1 \text{ M}\Omega \leq -1 \text{ V or } \geq 1 \text{ V} 12 \text{ bit} -ABUS: 5 \text{ VDC} =, \leq 4 \text{ Mbps} \cdot I/O \text{ to inner circu} Between channer Analog output ARIO-S-AO V1 2 \text{ CH, 4 \text{ CH model}} Voltage output -10 \text{ to 10 VDC} =$	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W \leq 15 mA (\leq 0.36 W) it: photocoupler insulated it: photocoupler insulated ARIO-S-AO \Box V2 10 to 10 VDC= ure: PV \pm 0.2% E S	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated ARIO-S-AO \Box C1 Current output 0 to 20 mA	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input method Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation Type Model Channel Output method Output method Output range	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $I/O \text{ to inner circuit}$ $A \text{ RIO-S-AI} \square \text{ V1}$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage input$ $-10 \text{ to 10 VDC} =$ $Room temperatt$ $Out of room tem$ $\geq 1 \text{ M}\Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12 -bit $-A \text{ BUS: 5 VDC} =, ;$ $-I/O \text{ co inner circu}$ $B \text{ Between channer}$ $A \text{ RIO-S-AO} \square \text{ V1}$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage output$ $A \text{ ARIO-S-AO} \square \text{ V1}$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage output$ $-10 \text{ to 10 VDC} =$ $Room temperatt$ $-Out of room temperatt$ $-Out of room temperatt$ $-Out of room temperatt$ $-Out of room temperatt$	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6% \geq 1 V \leq 180 mA (\leq 0.9 W 15 mA (\leq 0.9 W 15 mA (\leq 0.36 W) it: photocoupler insulated ARIO-S-AO \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. perature: PV \pm 0.6%	ulated ARIO-S-AI \Box C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated ARIO-S-AO \Box C1 Current output 0 to 20 mA % F.S.	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA ARIO-S-AO□C2 4 to 20 mA		
On delay time Off delay time Internal transmission speed Insulation Type Model Channel Input method Input method Input impedance Status indicator ON Resolution Power consumption Internal transmission speed Insulation Type Model Channel Output method Output method Output range Accuracy Load resistance	$\leq 0.5 \text{ ms}$ $\leq 1.5 \text{ ms}$ 4 Mbps $I/0 \text{ to inner circuit}$ $A nalog input$ $A RIO-S-AI \square V1$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage input$ $-10 \text{ to 10 VDC} =$ $Room temperatt$ $Out of room terr$ $\geq 1 M \Omega$ $\leq -1 \text{ V or } \geq 1 \text{ V}$ 12 -bit $-A BUS: 5 \text{ VDC} =, :$ $-I/O: 24 \text{ VDC} =, : \le 1000 \text{ J}$ 4 Mbps $-I/O \text{ to inner circu}$ $-Between channer$ $A nalog output$ $A RIO-S-AO \square V1$ $2 \text{ CH, 4 \text{ CH model}}$ $Voltage output$ $-10 \text{ to 10 VDC} =$ $-Room temperatt$ $-Out of room terr\geq 5 \text{ k} \Omega$	t: photocoupler insu ARIO-S-AI \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. sperature: PV \pm 0.6% 21 V 2180 mA (\leq 0.9 W 15 mA (\leq 0.9 W 15 mA (\leq 0.36 W) it: photocoupler insulated ARIO-S-AO \Box V2 10 to 10 VDC= ure: PV \pm 0.3% F.S. sperature: PV \pm 0.6%	ulated ARIO-S-AI \square C1 Current input 0 to 20 mA % F.S. $\leq 250 \Omega$ $\geq 1 mA$) sulated ARIO-S-AO \square C1 Current output 0 to 20 mA % F.S. $\leq 350 \Omega$	ARIO-S-AI□C2 4 to 20 mA ≥ 4 mA		
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Туре	Temperature input		
Model	ARIO-S-AI04TC ARIO-S-AI04RTD		
Channel	4 CH		
Input method	Voltage input	Resistance input	
Input range	Refer to the 'Input type and using rang	ge'	
Display accuracy ⁰¹⁾	(PV \pm 0.2% F.S. or \pm 2 °C, select the higher one) \pm 1-digit	(PV ±0.2% F.S.) ±1-digit	
Status indicator ON	Temperature input within the rated range		
Resolution / Display	16-bit/0.1 °C		
Power	• ABUS: 5 VDC=, ≤ 180 mA (≤ 0.9 W)		
consumption	• I/O: 24 VDC==, ≤ 15 mA (≤ 0.36 W)		
Internal transmission speed	4 Mbps		
Insulation	 I/O to inner circuit: photocoupler insu Between channels: non-insulated 	ulated	

• between ch 01) Refer to the 'Measurement accuracy' below

• Input type and using range

Input type		Using ran	ge (°	C)	Data display (dec)		
	K (CA)	-200.0	to	1350.0	-2000	to	13500
	J (IC)	-200.0	to	800.0	-2000	to	8000
	E (CR)	-200.0	to	800.0	-2000	to	8000
	T (CC)	-200.0	to	400.0	-2000	to	4000
	B (PR)	0.0	to	1800.0	00	to	18000
	R (PR)	0.0	to	1750.0	00	to	17500
Thermocouple	S (PR)	0.0	to	1750.0	00	to	17500
	N (NN)	-200.0	to	1300.0	-2000	to	13000
	C (TT) ⁰¹⁾	0.0	to	2300.0	00	to	23000
	G (TT) ⁰²⁾	0.0	to	2300.0	00	to	23000
	L (IC)	-200.0	to	900.0	-2000	to	9000
	U (CC)	-200.0	to	400.0	-2000	to	4000
	Platinel II	0.0	to	1390.0	00	to	13900
	Cu50 Ω	-200.0	to	200.0	-2000	to	2000
	Cu100 Ω	-200.0	to	200.0	-2000	to	2000
	JPt50 Ω	-200.0	to	650.0	-2000	to	6500
	JPt100 Ω	-200.0	to	650.0	-2000	to	6500
	JPt1000 Ω	-200.0	to	500.0	-2000	to	5000
RTD	DPt50 Ω	-200.0	to	650.0	-2000	to	6500
	DPt100 Ω	-200.0	to	650.0	-2000	to	6500
	DPt1000 Ω	-200.0	to	500.0	-2000	to	5000
	Nickel100 Ω	-50.0	to	200.0	-500	to	2000
	Nickel120 Ω	-50.0	to	200.0	-500	to	2000
	Nickel1000 Ω	-50.0	to	200.0	-500	to	2000

01) C(TT): Same as existing W5(TT) type sensor 02) G(TT): Same as existing W(TT) type sensor

Measurement accuracy

Input type	Using temperature	Measurement accuracy
Thermo -couple	At room temperature (23 ±5 °C)	• Thermocouple K, J, T, N, E below -100 °C and L, U, PLII: (PV ± 4 °C) ± 1 -digit • Thermocouple R, S below ± 200 °C : ± 4 °C ± 1 -digit • Thermocouple B below 400 °C: no accuracy standards • RTD Cu50 Ω , Cu100 Ω , Ni100 Ω , Ni100 Ω , Ni1000 Ω : (PV ± 2 °C) ± 1 -digit
RTD	Out of room temperature range	•Thermocouple: (PV ±0.5% F.S or ±7 °C higher one) ±1-digit •RTD: (PV ±0.5% F.S or ±3 °C higher one) ±1- digit

Туре		ABUS power sup	ABUS power supply					
Model		ARIO-P-B	ARIO-P-B					
Power s	upply	•ABUS (external consump.): 24 VDC==, \leq 320 mA (\leq 7.5 W, \leq 160 mA/CH, 2 CH/COM)						
		• ABUS (internal su	$(pply): 5 VDC = , \le 1$.,500 mA (≤ 7.5 W)				
Туре		I/O power supply						
Model		ARIO-P-F1	ARIO-P-F2	ARIO-P-T1	ARIO-P-T2			
	Voltage	$24 \text{VDC} = 10\% (\leq$	48 W)	-				
Input	Max. current	2,000 mA/CH, 2 CH	2,000 mA/CH, 2 CH/COM					
	Voltage	24 VDC== 10% (≤ 48 W)		24 VDC== 10% (≤ 48 W)				
Output	Max. current	2,000 mA/CH, 6 CH	I/COM	2,000 mA/CH, 8 CH/COM				

Common specifications

Insulation resistance	\geq 100 M Ω (500 VDC== megger)
Dielectric strength	1000 VAC~ 50/60 Hz for 1 min
Noise immunity	500 VDC the square wave noise (pulse width: 1 μs) by the noise simulator
Vibration	$0.7~\rm{mm}$ double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 1 hour
Vibration (malfunction)	$0.5\mathrm{mm}$ double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 10 min
Shock	300 m/s ² (\approx 30 G) in each X, Y, Z direction for 3 times
Shock (malfunction)	100 m/s² (\approx 10 G) in each X, Y, Z direction for 3 times
Ambient temperature	-10 to 55 °C, storage: -25 to 70 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP20 (IEC standard)
Material	Terminal: PA6, body: MPPO, base: PA6, POM
Installation method	DIN rail mounting
Certification	CE Busines K
Unit weight (packaged)	• Coupler: $\approx 165 \text{ g} (\approx 265 \text{ g})$ • Module: $\approx 75 \text{ g} (\approx 108 \text{ g})$